

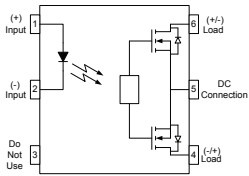
Parameter	Symbol	Rating	Units
Load Voltage	V _L	60	V
Load Current	I _L	3	A
On-Resistance	R _{on}	0.4	Ω
On-Resistance	V _{io}	3750	V _{rms}



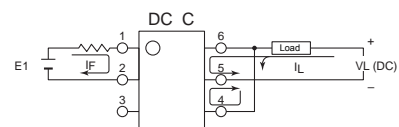
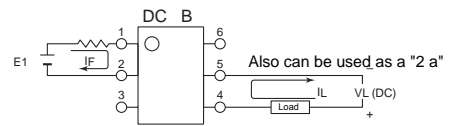
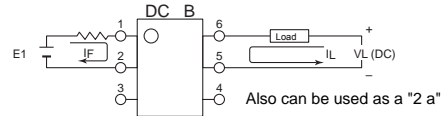
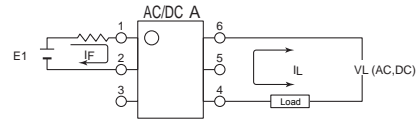
SMD-6



DIP-6



1. LED Anode
2. LED Cathode
4. Drain (MOS FET)
5. Source (MOS FET)
6. Drain (MOS FET)



APSEMI PhotoRelays

APSEMI Photorelays are the most reliable, technically advanced logic-to-power interface devices. Their basic function is to take a low current signal from a microprocessor to control the switching of both AC and DC loads, while providing an isolation barrier between logic and power. While this function is common to all relays, Photorelays provide distinct advantages over their mechanical counterparts including:

- Long life (No limit on mechanical and electrical lifetime)
- Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI
- No have voltaic arc, bounce, and noise
- More resistant to vibration and impact
- AC or DC load switching
- Small package size

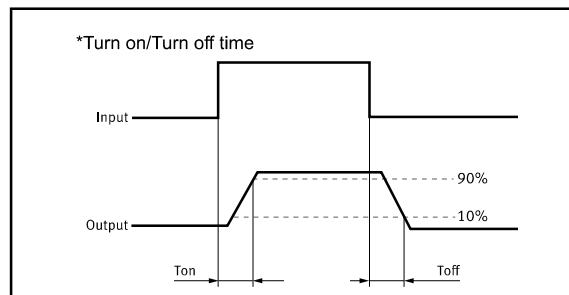
Applications

These advantages make APSEI Photorelays the ideal choice for:

- Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems
- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

TPYES

Category	Output Rating		Package	Part No.	Packing Quantity
	Load Voltage	Load Current			
AC/DC	60V	3A	DIP-6	APV252G3E	50pcs /tube
			SMD-6	APV252G3EH	1000pcs /reel



**Absolute Maximum Ratings** (Ta = 25°C)

Item		Symbol	Value	Units	Note
Input	Continuous LED Current	I _F	50	mA	
	Peak LED Current	I _{FP}	500	mA	f=100Hz, duty=1%
	LED Reverse Voltage	V _R	5	V	
	Input Power Dissipation	P _{In}	75	mW	
Output	Load Voltage	V _L	60	V(AC peak or DC)	
	Load Current	I _L	3	A	
	Peak Load Current	I _{Peak}	6.0	A	100ms(1 pulse)
	Output Power Dissipation	P _{out}	500	mW	
Total Power Dissipation		P _T	550	mW	
I/O Breakdown Voltage		V _{I/O}	3750	V _{rms}	RH=60%, 1min
Operating Temperature		T _{opr}	-40 to 85	°C	
Storage Temperature		T _{stg}	-40 to 100	°C	
Pin Soldering Temperature		T _{sol}	260	°C	10 sec max.

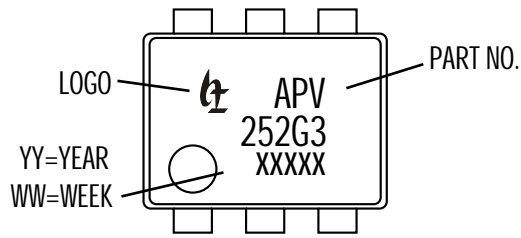
Electrical Characteristics (Ta = 25°C)

Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
Input	LED Forward Voltage	V _F		1.3	3.0	V	I _F =10mA
	Operation LED Current	I _{Fon}		1.2	2.0	mA	
	Recovery LED Current	I _{Foff}		0.3	0.9	mA	
	Recovery LED Voltage	V _{Foff}	0.7			V	
Output	On-Resistance	R _{on}		0.04	0.052	Ω	I _F =5mA, I _L =Rating, Time to flow is within 1 sec.
	Off-State Leakage Current	I _{Leak}			1.0	uA	V _L =Rating
	Output Capacitance	C _{out}		500		pF	V _L =0, f=1MHz
Transmis sion	Turn-On Time	T _{on}		0.8	5.0	ms	I _F =10mA, I _L =100mA,
	Turn-Off Time	T _{off}		0.1	1.0	ms	
Coupled	I/O Isolation Resistance	R _{I/O}	10 ¹⁰			Ω	DC500V
	I/O Capacitance	C _{I/O}		0.8	1.3	pF	f=1MHz



Dimensions and DIP-6 Package Unit: mm

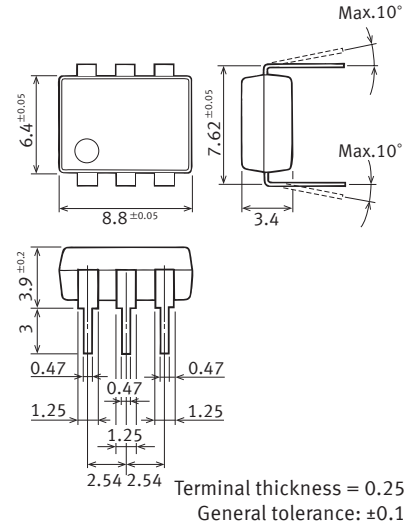
Marking



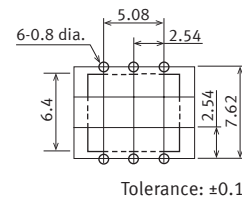
Lable



Through hole terminal type

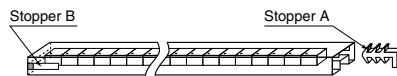


PC board pattern (Bottom view)



DIP Tape dimensions Unit: mm

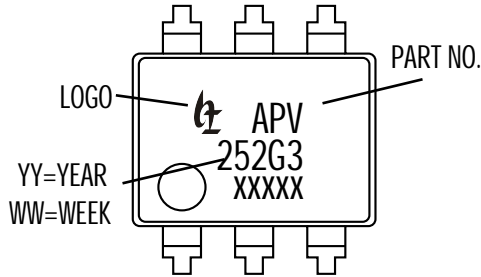
Devices are packaged in a tube so that pin No. 1 is on the stopper B side. Observe correct orientation when mounting them on PC boards.



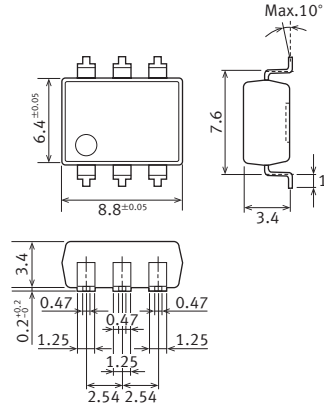


Dimensions and SMD-6 Package Unit: mm

Marking



Surface mount terminal type

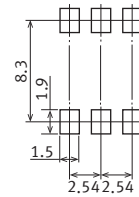


Terminal thickness = 0.25
General tolerance: ±0.1

Lable



Recommended mounting pad (Top view)



Tolerance: ±0.1

Tape dimensions (tape reel)

